# **Dual General Purpose Transistor**

## **PNP Dual**

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-563 which is designed for low power surface mount applications.

#### **Features**

- Lead–Free Solder Plating
- Low  $V_{CE(SAT)}$ , < 0.5 V
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	-60	V
Collector - Base Voltage	V <sub>CBO</sub>	-50	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6.0	V
Collector Current – Continuous	I <sub>C</sub>	-100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	357 (Note 1) 2.9 (Note 1)	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	350 (Note 1)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	500 (Note 1) 4.0 (Note 1)	mW mW/°C
Thermal Resistance,	$R_{\theta JA}$	250	°C/W
Junction-to-Ambient	0071	(Note 1)	

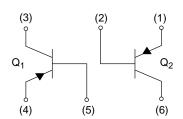
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 @ Minimum Pad.



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SOT-563 CASE 463A STYLE 1

## **MARKING DIAGRAM**



3T = Specific Device Code

M = Month Code

= Pb–Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector–Base Breakdown Voltage (I <sub>C</sub> = –50 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)</sub> CBO	-60	-	-	Vdc
Collector–Emitter Breakdown Voltage $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	-50	-	-	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = –50 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)EBO</sub>	-6.0	-	-	Vdc
Collector–Base Cutoff Current $(V_{CB} = -30 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	-	-	-0.5	nA
Emitter–Base Cutoff Current (V <sub>EB</sub> = -5.0 Vdc, I <sub>B</sub> = 0)	I <sub>EBO</sub>	-	-	-0.5	μА
Collector–Emitter Saturation Voltage (Note 2) (I <sub>C</sub> = -50 mAdc, I <sub>B</sub> = -5.0 mAdc)	V <sub>CE(sat)</sub>	-	-	-0.5	Vdc
DC Current Gain (Note 2) $(V_{CE} = -6.0 \text{ Vdc}, I_C = -1.0 \text{ mAdc})$	h <sub>FE</sub>	120	_	560	_
Transition Frequency $(V_{CE} = -12 \text{ Vdc}, I_{C} = -2.0 \text{ mAdc}, f = 30 \text{ MHz})$	f <sub>T</sub>	-	140	_	MHz
Output Capacitance $(V_{CB} = -12 \text{ Vdc}, I_E = 0 \text{ Adc}, f = 1 \text{ MHz})$	C <sub>OB</sub>	-	3.5	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, D.C.  $\leq$  2%.

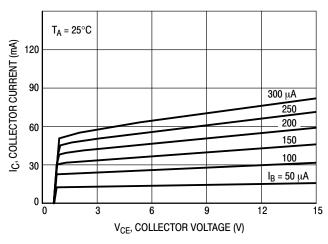
## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
EMT1DXV6T1G	SOT-563 (Pb-Free)	4000 / Tape & Reel
NSVEMT1DXV6T1G*	SOT-563 (Pb-Free)	4000 / Tape & Reel
EMT1DXV6T5G	SOT-563 (Pb-Free)	8000 / Tape & Reel
NSVEMT1DXV6T5G*	SOT-563 (Pb-Free)	8000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.

## **TYPICAL CHARACTERISTICS**



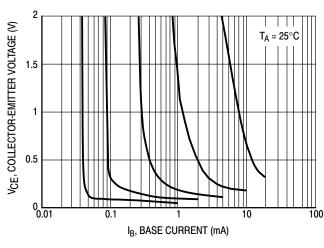
1000

T<sub>A</sub> = 75°C

T<sub>A</sub> = 25°C

Figure 1. I<sub>C</sub> – V<sub>CE</sub>

Figure 2. DC Current Gain



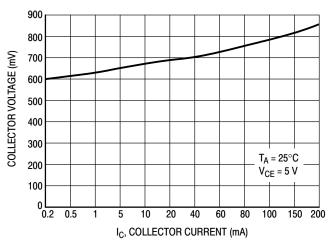
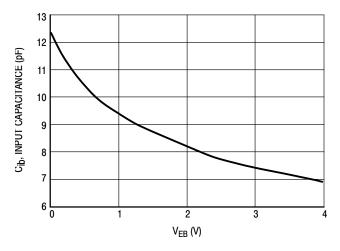


Figure 3. Collector Saturation Region

Figure 4. On Voltage



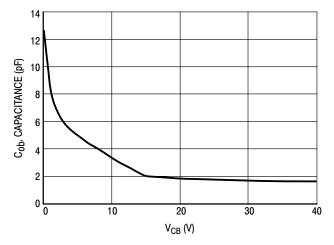
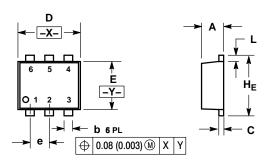


Figure 5. Capacitance

Figure 6. Capacitance

#### PACKAGE DIMENSIONS

## SOT-563, 6 LEAD CASE 463A ISSUE F



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD
  FINISH THICKNESS. MINIMUM LEAD THICKNESS
  IS THE MINIMUM THICKNESS OF BASE MATERIAL.

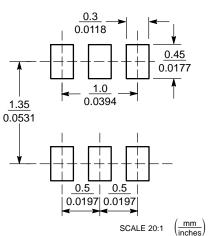
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
Е	1.10	1.20	1.30	0.043	0.047	0.051
е	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

STYLE 1: PIN 1. EMITTER 1

2. BASE 13. COLLECTOR 24. EMITTER 2

BASE 2 COLLECTOR 1

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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